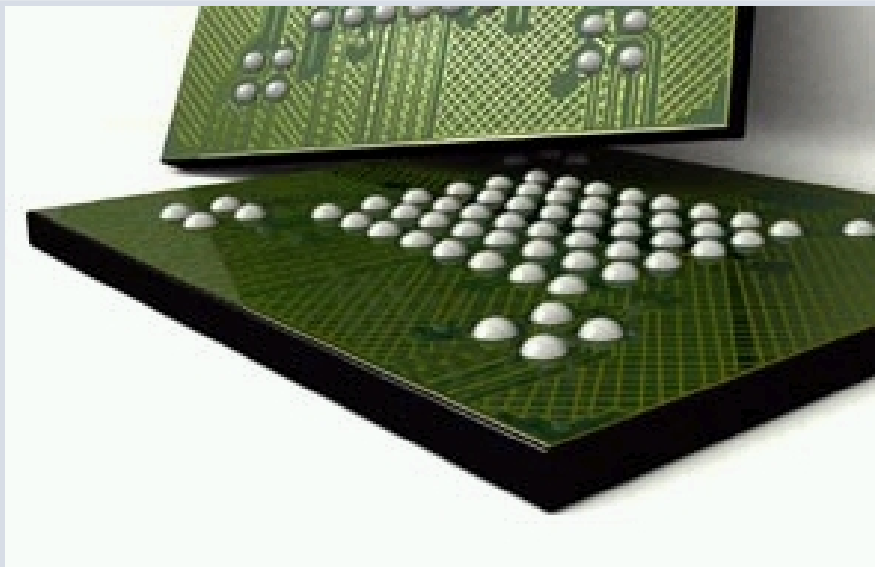


## 2Gb Mass Storage : MT29F2G16ABDHC-ET

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### SPECIFICATIONS

**Density:** 2Gb  
**Part Status:** Production  
**RoHS:** Yes  
**Depth:** 128Mb  
**Width:** x16  
**Voltage:** 1.8V  
**Package:** VFBGA  
**Pin Count:** 63-ball  
**I/O:** Common  
**Op. Temp.:** -40C to +85C

### DESCRIPTION

Micron NAND Flash uses an industry proven floating gate cell and a standard interface to enable pin and function drop-in compatibility and easy integration into most existing designs.

**RoHS-Compliant:** This part meets internationally recognized Pbfree standards, including RoHS.

[RoHS Certificate of Compliance](#)

[China RoHS Certificate](#)

Illustration only. See data sheet for product specifications.

Orderable Part	Part Status	Buy Samples	Distributor Stock
MT29F2G16ABDHC-ET:D	Production	<a href="#">Contact Rep</a>	<a href="#">Contact Rep</a>

Please note: Distributor inventory is an estimate and may not reflect actual available inventory.

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